Diode Semiconductor Device - Page 1 of 1



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# **Inclosure Material:**

Metal

# **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

# Mounting Method:

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

6.8 regulator voltage

# Current Rating Per Characteristic:

37.00 amperes forward current, average peak and 7.00 amperes repetitive peak forward current

# Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead

# **Specification Data:**

81349-mil-s-19500/114 government specification

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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